

/

IDM

7	28	2020		2020	
30.63		16.03%	4.03		145.27%
	3.45		466.46%		

IDM				2020	1/2	
30.63		16.03%		IDM	13.9	
	20.11%			16.77		
02.78%	d	27.3%	20	6.63		

4

IDM			
IGBT	49.90%	MOSFET	21.43%
50%	IDM		
	11.5%		
	27.3%	6.63	
		2019	
IDM	44.71%	43.18%	

1

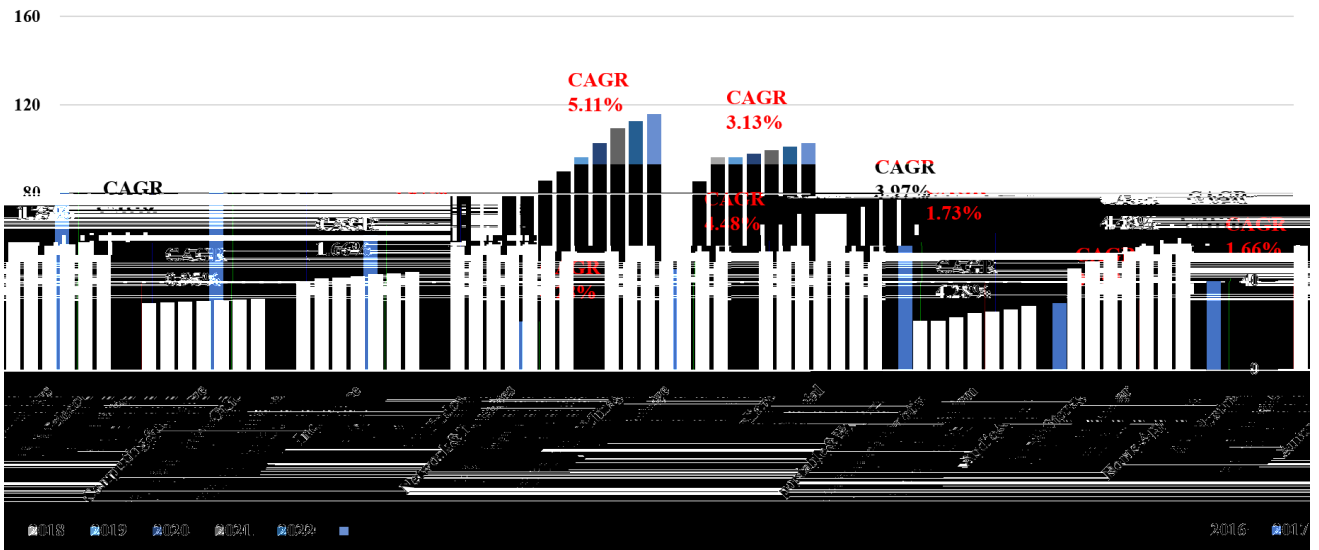
单位: 万元		2019H1	2019H2	2019H3	2019H4	同比 (2019H3-2019H2)	环比 (2019H3-2019H2)
169629.99	1074076.32	123389.01	111100.77	111181.18	111181.18	0.00%	0.00%
128524.31	109532.49	3.35%		-14.78%			
2.09	36331.90	41178.30	11.50%	13.34%			
105984.39					36930.19		*7326
5%	产品与方案	114006.51	251566.21	137559.70	136938.18	20.11%	-0.4
0%	封装测试	103702.72	103601.40	104117.67	105737.01	20.21%	1.7
9%	其他	-61.72%	-66.59%	5019.73	10771.86	5752.13	1921.5
7%	其他业务	28.34%	-44.05%	1323.84	4360.16	3036.32	1698.9
04002306376	22.15742/8.410/11.0	11.01306	1.5%	16.03%		-1.28%	

Wind

1200V 650V SiC
6 SiC

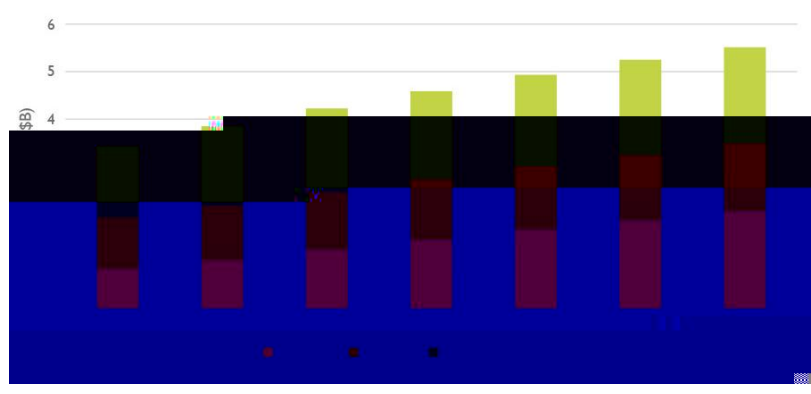
2 MOSFET

2016-2022功率MoSFET细分应用市场规模预测（亿元）



Yole

3 IGBT



Yole

2018 1 2016 4 2016 2017

“ ”

AA ABS R3 A B

“ ”

	6	15%	
	6	5%	15%
	6	-5%	5%
	6	5%	15%
	6	15%	
	6		
	6		
	6		

<http://www.nesc.cn> 400-600-0686

6666			130119
28	D		100033
729			200127
1006	34D		518038
	122	15	510630

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